

CEDM8001

**SURFACE MOUNT
P-CHANNEL
ENHANCEMENT-MODE
SILICON MOSFET**



www.centrasemi.com



Top View Bottom View

SOT-883L CASE

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CEDM8001 is an P-Channel Enhancement-mode Field Effect Transistor, manufactured by the P-Channel DMOS Process, designed for high speed pulsed amplifier and driver applications. This MOSFET offers Low $r_{DS(on)}$ and Low Theshold Voltage.

MARKING CODE: F

FEATURES:

- 100mW Power Dissipation
- 0.4mm Low Package Profile
- Low $r_{DS(on)}$
- Low Threshold Voltage
- Logic Level Compatible
- Small, TLP™ 1x0.6mm, SOT-883L Leadless Surface Mount Package

APPLICATIONS:

- Load/Power Switches
- DC/DC Converters
- Battery Powered Portable Equipment

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Drain-Source Voltage
Gate-Source Voltage
Continuous Drain Current (Steady State)
Continuous Drain Current
Power Dissipation
Operating and Storage Junction Temperature

SYMBOL

V_{DS}	20
V_{GS}	10
I_D	100
I_D	200
P_D	100
T_J, T_{stg}	-65 to +150

UNITS

V
V
mA
mA
mW
$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_{GSSF}	$V_{GS}=10V, V_{DS}=0$			1.0	μA
I_{GSSR}	$V_{GS}=10V, V_{DS}=0$			1.0	μA
I_{DSS}	$V_{DS}=20V, V_{GS}=0$			1.0	μA
BV_{DSS}	$V_{GS}=0, I_D=100\mu\text{A}$	20			V
$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu\text{A}$	0.6		1.1	V
$r_{DS(ON)}$	$V_{GS}=4.0V, I_D=10\text{mA}$			8.0	Ω
$r_{DS(ON)}$	$V_{GS}=2.5V, I_D=10\text{mA}$			12	Ω
$r_{DS(ON)}$	$V_{GS}=1.5V, I_D=1.0\text{mA}$			45	Ω
g_{fs}	$V_{DS}=10V, I_D=100\text{mA}$	100			mS
C_{rss}	$V_{DS}=3.0V, V_{GS}=0, f=1.0\text{MHz}$		15		pF
C_{iss}	$V_{DS}=3.0V, V_{GS}=0, f=1.0\text{MHz}$		45		pF
C_{oss}	$V_{DS}=3.0V, V_{GS}=0, f=1.0\text{MHz}$		15		pF
t_{on}	$V_{DD}=3.0V, V_{GS}=2.5V, I_D=10\text{mA}$		35		ns
t_{off}	$V_{DD}=3.0V, V_{GS}=2.5V, I_D=10\text{mA}$		80		ns

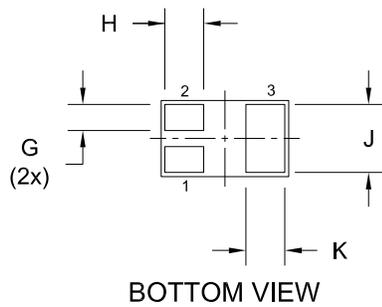
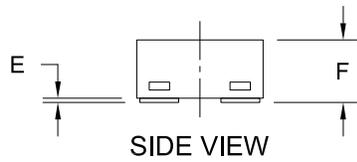
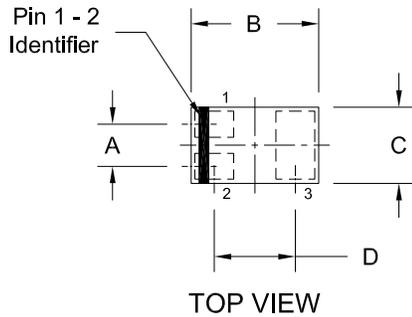
R5 (5-August 2010)

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SOT-883L CASE - MECHANICAL OUTLINE



DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.014		0.35	
B	0.037	0.041	0.95	1.05
C	0.022	0.026	0.55	0.65
D	0.026		0.65	
E	0.000	0.002	0.00	0.05
F	0.012	0.016	0.30	0.40
G	0.005	0.007	0.13	0.18
H	0.008	0.012	0.20	0.30
J	0.018	0.022	0.45	0.55
K	0.008	0.012	0.20	0.30

SOT-883L (REV:R2)

LEAD CODE:

- 1) GATE
- 2) SOURCE
- 3) DRAIN

MARKING CODE: F

R2

R5 (5-August 2010)